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## **Certificate of Analysis**

MRA Report #: M16-112T  
Report Date: November 12, 2016  
Report Type: EESU Capacitor Performance Testing  
Prepared for: Mr. Ian Clifford  
EESor, Inc.  
715 Discovery Boulevard #107  
Cedar Park, TX 78613

### **The following samples were submitted and identified on behalf of the client as:**

Sample ID's: Sample #1 – 3000Vdc rated bare prototype capacitor layer (single dot)  
Sample #2 – 3000Vdc rated bare prototype capacitor layer (double dot)  
Sample #3 – 3000Vdc rated packaged prototype capacitor, 4 layers  
Sample #4 – 3000Vdc rated packaged prototype capacitor, 8 layers  
Sample #5 – 3000Vdc rated packaged prototype capacitor, 16 layers

Material types: Prototype EESU capacitors  
Quantity: One per sample

Testing Period: November 9, 2016 – November 11, 2016

Objective: To independently illustrate the performance of EESor capacitors across the range of operating conditions

Performed tests: Capacitance vs. DC Voltage  
Insulation Resistance vs. DC Voltage  
Capacitance vs. Frequency

Summary: The results are given on the following pages for information only.

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**Test Results:**

**CAPACITANCE VS. DC VOLTAGE**

**Sample #1 - 3000Vdc rated bare prototype capacitor layer (single dot)**

Voltage, Vdc	Time Constant, ms			Discharge Resistor, MΩ	Estimated Capacitance, nF				
	$\tau_1$	$\tau_2$	$\tau_3$		C <sub>1</sub>	C <sub>2</sub>	C <sub>3</sub>	Mean	$\sigma$
<b>500</b>	14.4	13.4	13.7	12.120	1.19	1.11	1.13	1.14	0.042
<b>1000</b>	14.3	13.1	13.7	12.120	1.18	1.08	1.13	1.13	0.050
<b>2000</b>	12.2	13.0	12.7	12.120	1.01	1.07	1.05	1.04	0.033
<b>3000</b>	11.9	11.7	11.8	12.120	0.98	0.97	0.97	0.97	0.008
Measured uncertainty: Capacitance $\pm 0.07$ nF, Voltage $\pm 1.0$ Vdc									

**Sample #2 - 3000Vdc rated bare prototype capacitor layer (double dot)**

Voltage, Vdc	Time Constant, ms			Discharge Resistor, MΩ	Estimated Capacitance, nF				
	$\tau_1$	$\tau_2$	$\tau_3$		C <sub>1</sub>	C <sub>2</sub>	C <sub>3</sub>	Mean	$\sigma$
<b>500</b>	13.1	12.9	13.1	12.120	1.08	1.06	1.08	1.08	0.010
<b>1000</b>	12.7	13.4	12.7	12.120	1.05	1.11	1.05	1.07	0.033
<b>2000</b>	12.0	11.6	12.4	12.120	0.99	0.96	1.02	0.99	0.033
<b>3000</b>	12.2	11.2	10.8	12.120	1.01	0.92	0.89	0.94	0.059
Measured uncertainty: Capacitance $\pm 0.07$ nF, Voltage $\pm 1.0$ Vdc									

**Sample #3 - 3000Vdc rated packaged prototype capacitor, 4 layers**

Voltage, Vdc	Time Constant, ms			Discharge Resistor, MΩ	Estimated Capacitance, nF				
	$\tau_1$	$\tau_2$	$\tau_3$		C <sub>1</sub>	C <sub>2</sub>	C <sub>3</sub>	Mean	$\sigma$
<b>500</b>	16.4	15.5	16.0	12.120	1.35	1.28	1.32	1.32	0.037
<b>1000</b>	16.7	15.4	15.4	12.120	1.38	1.27	1.27	1.31	0.062
<b>2000</b>	15.3	16.9	15.6	12.120	1.26	1.39	1.29	1.31	0.070
<b>3000</b>	16.2	16.1	16.0	12.120	1.34	1.33	1.32	1.33	0.008
Measured uncertainty: Capacitance $\pm 0.08$ nF, Voltage $\pm 1.0$ Vdc									

**Sample #4 - 3000Vdc rated packaged prototype capacitor, 8 layers**

Voltage, Vdc	Time Constant, ms			Discharge Resistor, MΩ	Estimated Capacitance, nF				
	$\tau_1$	$\tau_2$	$\tau_3$		C <sub>1</sub>	C <sub>2</sub>	C <sub>3</sub>	Mean	$\sigma$
<b>500</b>	42.0	38.8	37.6	12.120	3.47	3.20	3.10	3.26	0.188
<b>1000</b>	39.6	38.1	38.8	12.120	3.27	3.14	3.20	3.20	0.062
<b>2000</b>	39.6	36.8	37.3	12.120	3.27	3.04	3.08	3.13	0.123
<b>3000</b>	36.8	36.8	36.6	12.120	3.04	3.04	3.02	3.03	0.010
Measured uncertainty: Capacitance $\pm 0.08$ nF, Voltage $\pm 1.0$ Vdc									

**Sample #5 - 3000Vdc rated packaged prototype capacitor, 16 layers**

Voltage, Vdc	Time Constant, ms			Discharge Resistor, MΩ	Estimated Capacitance, nF				
	$\tau_1$	$\tau_2$	$\tau_3$		C <sub>1</sub>	C <sub>2</sub>	C <sub>3</sub>	Mean	$\sigma$
<b>500</b>	90.0	88.0	88.0	12.120	7.43	7.26	7.26	7.32	0.095
<b>1000</b>	93.1	86.1	85.5	12.120	7.68	7.10	7.05	7.28	0.349
<b>2000</b>	91.0	89.5	92.5	12.120	7.51	7.38	7.63	7.51	0.124
<b>3000</b>	93.0	94.0	92.0	12.120	7.67	7.76	7.59	7.67	0.083
Measured uncertainty: Capacitance $\pm 0.10$ nF, Voltage $\pm 1.0$ Vdc									

**INSULATION RESISTANCE VS. DC VOLTAGE**

**Sample #1 - 3000Vdc rated bare prototype capacitor layer (single dot)**

Voltage, Vdc	Leakage Current, nA			Estimated Insulation Resistance, GΩ					Estimated Mean Capacitance, nF	Estimated Self-Discharge Time Constant, s
	I <sub>1</sub>	I <sub>2</sub>	I <sub>3</sub>	IR <sub>1</sub>	IR <sub>2</sub>	IR <sub>3</sub>	Mean	σ		
<b>500</b>	5.5	1.2	1.3	90.9	416.7	384.6	297.4	179.54	1.14	339.0
<b>1000</b>	14.2	5.9	5.2	70.4	169.5	192.3	144.1	64.80	1.13	162.8
<b>2000</b>	26.2	17.2	15.4	76.3	116.3	129.9	107.5	27.83	1.04	111.8
<b>3000</b>	47.6	39.6	29.9	63.0	75.8	100.3	79.7	18.97	0.97	77.3

Measured uncertainty: Leakage Current ±1.6nA, Voltage ±1.0Vdc

**Sample #2 - 3000Vdc rated bare prototype capacitor layer (double dot)**

Voltage, Vdc	Leakage Current, nA			Estimated Insulation Resistance, GΩ					Estimated Mean Capacitance, nF	Estimated Self-Discharge Time Constant, s
	I <sub>1</sub>	I <sub>2</sub>	I <sub>3</sub>	IR <sub>1</sub>	IR <sub>2</sub>	IR <sub>3</sub>	Mean	σ		
<b>500</b>	5.9	1.3	1.2	84.7	384.6	416.7	295.3	183.08	1.08	318.9
<b>1000</b>	17.2	6.1	5.7	58.1	163.9	175.4	132.5	64.66	1.07	141.8
<b>2000</b>	27.4	19.5	16.8	73.0	102.6	119.0	98.2	23.34	0.99	97.2
<b>3000</b>	43.2	37.1	29.5	69.4	80.9	101.7	84.0	16.35	0.94	79.0

Measured uncertainty: Leakage Current ±1.6nA, Voltage ±1.0Vdc

Note: Estimated mean capacitance value taken from average measurements on page #2.

**Sample #3 - 3000Vdc rated packaged prototype capacitor, 4 layers**

Voltage, Vdc	Leakage Current, nA			Estimated Insulation Resistance, GΩ					Estimated Mean Capacitance, nF	Estimated Self-Discharge Time Constant, s
	I <sub>1</sub>	I <sub>2</sub>	I <sub>3</sub>	IR <sub>1</sub>	IR <sub>2</sub>	IR <sub>3</sub>	Mean	σ		
<b>500</b>	9.9	0.16	0.21	50.5	3125.0	2381.0	1852.2	1604.01	1.32	2445
<b>1000</b>	19.8	6.6	6.5	50.5	151.5	153.8	118.6	59.00	1.31	155
<b>2000</b>	39.7	23.6	19.9	50.4	84.7	100.5	78.5	25.63	1.31	103
<b>3000</b>	59.9	57.4	53.7	50.1	52.3	55.9	52.7	2.92	1.33	70

Measured uncertainty: Leakage Current ±1.6nA, Voltage ±1.0Vdc

**Sample #4 - 3000Vdc rated packaged prototype capacitor, 8 layers**

Voltage, Vdc	Leakage Current, nA			Estimated Insulation Resistance, GΩ					Estimated Mean Capacitance, nF	Estimated Self-Discharge Time Constant, s
	I <sub>1</sub>	I <sub>2</sub>	I <sub>3</sub>	IR <sub>1</sub>	IR <sub>2</sub>	IR <sub>3</sub>	Mean	σ		
<b>500</b>	12.3	0.2	0.3	40.7	2500.0	1666.7	1402.4	1250.78	3.26	4572
<b>1000</b>	22.7	7.3	5.8	44.1	137.0	172.4	117.8	66.29	3.20	377
<b>2000</b>	48.1	29.2	23.8	41.6	68.5	84.0	64.7	21.48	3.13	203
<b>3000</b>	76.5	64.4	59.2	39.2	46.6	50.7	45.5	5.81	3.03	138

Measured uncertainty: Leakage Current ±1.6nA, Voltage ±1.0Vdc

**Sample #5 - 3000Vdc rated packaged prototype capacitor, 16 layers**

Voltage, Vdc	Leakage Current, nA			Estimated Insulation Resistance, GΩ					Estimated Mean Capacitance, nF	Estimated Self-Discharge Time Constant, s
	I <sub>1</sub>	I <sub>2</sub>	I <sub>3</sub>	IR <sub>1</sub>	IR <sub>2</sub>	IR <sub>3</sub>	Mean	σ		
<b>500</b>	18.4	0.3	0.3	27.2	1666.7	1666.7	1120.2	946.56	7.32	8200
<b>1000</b>	39.1	15.7	9.0	25.6	63.7	111.1	66.8	42.85	7.28	486
<b>2000</b>	84.1	51.3	44.6	23.8	39.0	44.8	35.9	10.87	7.51	270
<b>3000</b>	147.2	122.5	100.1	20.4	24.5	30.0	24.9	4.81	7.67	191

Measured uncertainty: Leakage Current ±1.6nA, Voltage ±1.0Vdc

Note: Estimated mean capacitance value taken from average measurements on page #3.

**CAPACITANCE VS. FREQUENCY**

**Sample #1 - 3000Vdc rated bare prototype capacitor layer (single dot)**

Frequency, kHz	Capacitance, nF
1000	0.949
800	0.951
600	0.955
500	0.957
400	0.961
300	0.966
200	0.973
100	0.985
80	0.989

**Sample #2 - 3000Vdc rated bare prototype capacitor layer (double dot)**

Frequency, kHz	Capacitance, nF
1000	0.888
800	0.890
600	0.894
500	0.896
400	0.899
300	0.904
200	0.912
100	0.923
80	0.927

**ACTIVE DIELECTRIC LAYER THICKNESS**

(For reference only. Data provided by EESstor, Inc.)

Sample #	Active Dielectric Layer Thickness, μm
Sample #1	64.7
Sample #2	75.0
Sample #3	72.1
Sample #4	75.4
Sample #5	69.2

## Test Methods

The below methods are used to perform the tests.

### General

All measurement equipment is powered up at least 30 minutes prior to testing and allowed to reach a stable temperature.

### Capacitance vs. DC Voltage

Capacitance is measured with capacitors charged to a desired voltages. The method employed is based upon determination of the time constant,  $\tau$  of an RC circuit, by means of a controlled discharge.

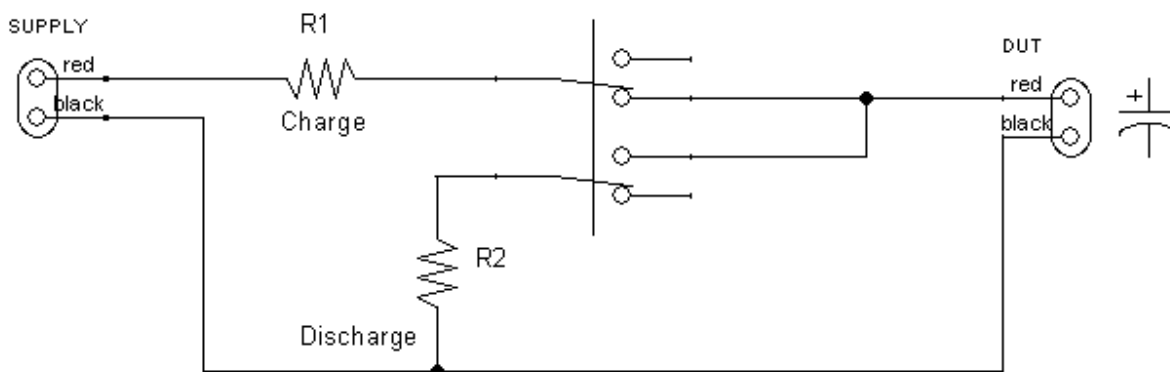


Figure 1: Capacitor charge/discharge circuit.

An oscilloscope (Tektronix TDS 2004B) is connected across the device under test using a 1000x probe (Tektronix P6015A) to provide necessary voltage rating and sufficiently high probe impedance. The contribution of the oscilloscope probe and any other parasitic resistance is taken into account for the purposes of final calculations by means of a direct resistance measurement of the discharge path.

The capacitors is charged to operating voltage using a high voltage power supply (Stanford Research Power Supply PS350). The oscilloscope is used to measure the discharge time in which the voltage between the capacitor terminals is reduced by 63.2%.

Based on the measured resistance and time constant, capacitance is determined using the below equation:

$$C = \frac{\tau}{R}$$

Each measurement is taken three times for each test voltages.

### Insulation Resistance vs. DC Voltage

The leakage through the dielectric is measured by means of applying a static voltage using a high voltage power supply (Stanford Research Power Supply PS350) across the device under test with a sensitive current meter (Keithley Picoammeter 6485) connected in series. In accordance with the manufacturer's recommendations, a network of diodes and a resistor are used to protect the meter from potential voltages in excess of 200V.

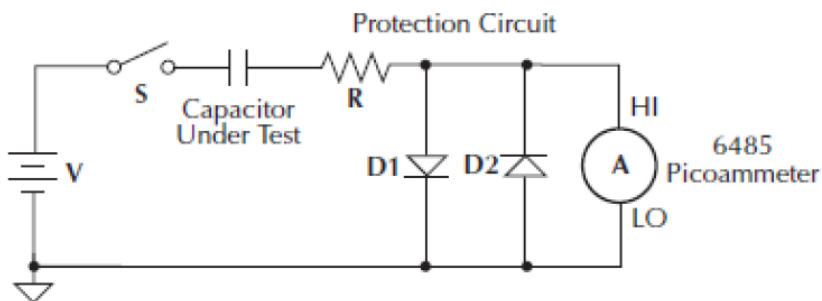


Figure 2. Manufacture recommended circuit for >200V capacitor measurement.

The capacitor is allowed to settle after application of voltage for a minimum of 5 minutes before the leakage current is recorded.

### Capacitance vs. Frequency

The dependence of capacitance versus frequency is measured a commercial impedance analyzer (Keysight E4980A Precision LCR Meter). Capacitance is measured in parallel mode in a frequency range from 80kHz to 1.0MHz at 1Vrms, 0V dc-bias test conditions using a tweezers contact probe. Open/short correction is performed prior to measurement in order to compensate for stray admittance and residual impedance in the probe.

Measurements were conducted both at MRA Laboratories, Inc, 15 Print Works Drive, Adams, MA 01220 and at EESor, Inc. 715 Discovery Blvd, Ste. 107, Cedar Park, TX 78613.



**Affirmation:** I certify the above to be true and correct and to have witnessed the testing as described



Anton Polotai, Senior Scientist

Cc: RM, SM, JW

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